

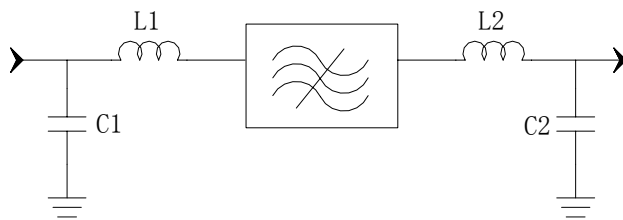
Specifications

Parameter	Unit	Minimum	Typical	Maximum
Center Frequency	MHz	237.85	238	238.15
Insertion Loss	dB	-	24.8	27
3 dB Bandwidth	MHz	6	6.1	-
45 dB Bandwidth	MHz	-	8.17	8.2
Passband Variation	dB	-	0.8	0.9
Absolute Delay	usec	-	2.109	-
Ultimate Rejection	dB	45	47	-
Material Temperature coefficient	KHz/°C	0.238		
Ambient Temperature	°C	25		
Package Size	DIP2712 (27.0x12.8x4.7mm3)			


Notes:

1. All specifications are based on the test circuit shown
2. In production, devices will be tested at room temperature to a guardbanded specification to ensure electrical compliance over temperature
3. Electrical margin has been built into the design to account for the variations due to temperature drift and manufacturing tolerances
4. This is the optimum impedance in order to achieve the performance show

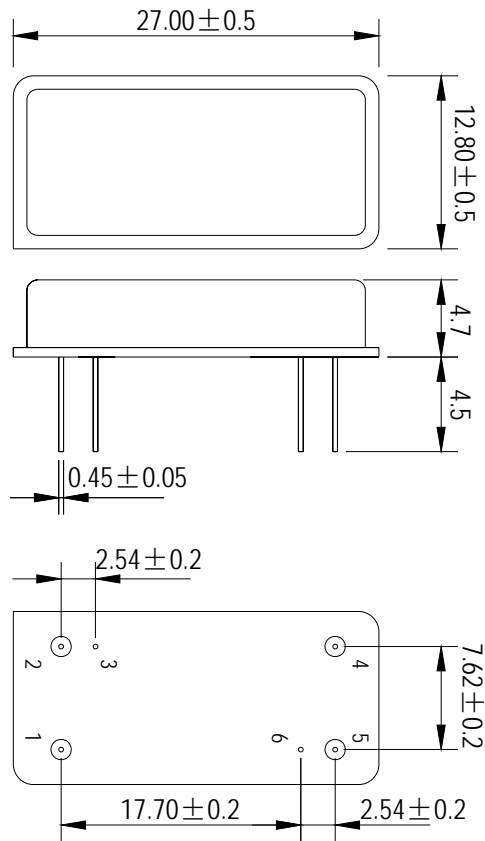
Matching Configuration




L1=L2=39nH
C1=12pF C2=33pF
Source/Load Impedance=50 ohm
 Notes - Component values may change depending
 on board layout.

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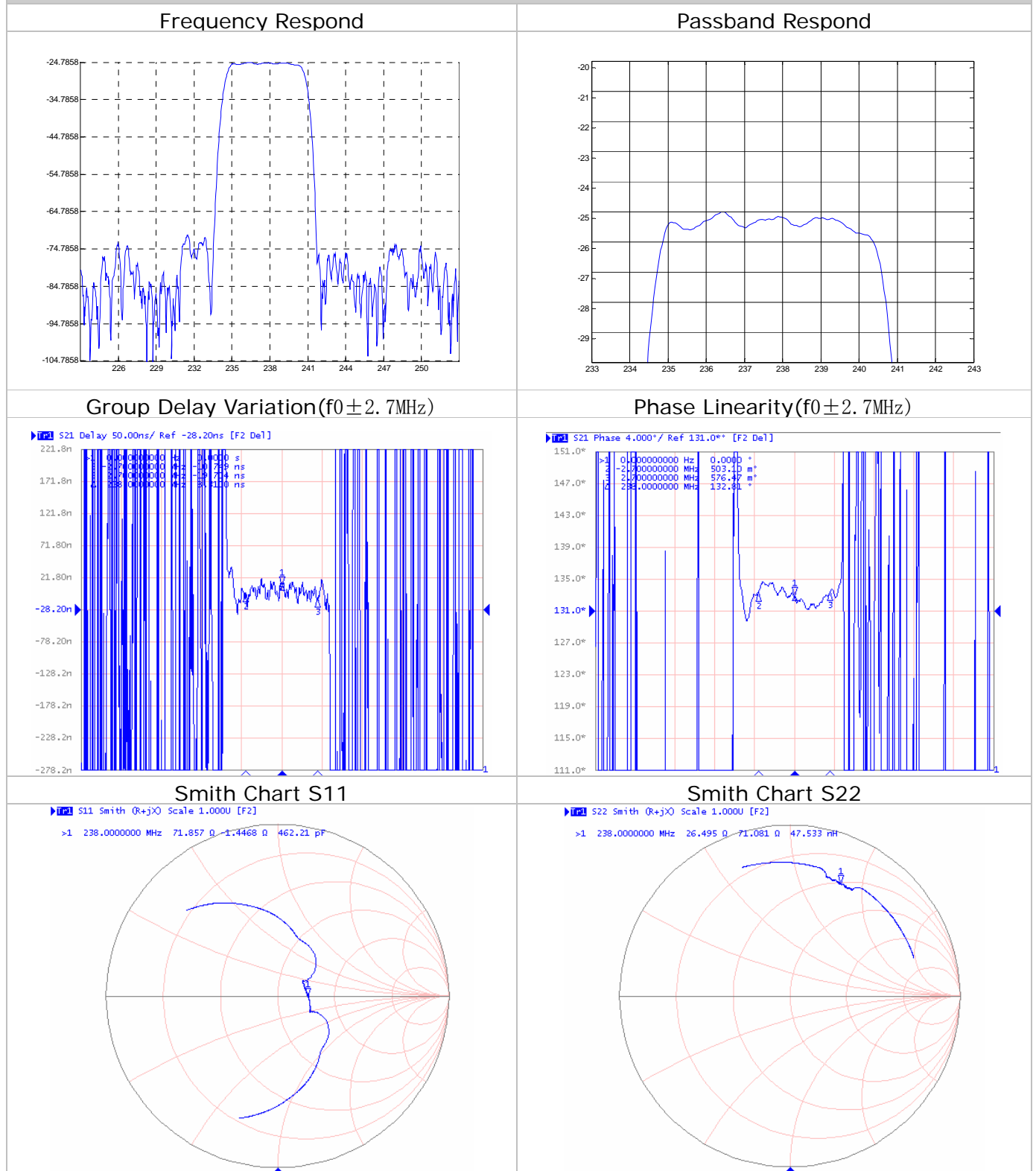
Package Dimension



Input:1
Output:5

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Typical Performance



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